



YOUSHANG SEMICONDUCTOR

**设计研发新型功率器件**

**各类小信号开关**

**中低压及高压大电流等场效应管**

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## Features

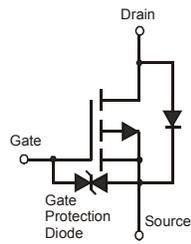
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- 

## Mechanical Data

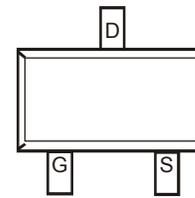
- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound.  
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish - Matte Tin Annealed over Alloy 42 Leadframe.  
Solderable per MIL-STD-202, Method 208
- Weight: 0.006 grams (Approximate) <sup>③</sup>



Top View



Equivalent Circuit



Top View

**Maximum Ratings** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			$V_{DSS}$	-20	V
Gate-Source Voltage			$V_{GSS}$	$\pm 6$	V
Continuous Drain Current (Note 5)	Steady State	$T_A = +25^\circ\text{C}$	$I_D$	-0.82	A
		$T_A = +85^\circ\text{C}$		-0.54	
Pulsed Drain Current (Note 6)			$I_{DM}$	-3	A

**Thermal Characteristics**

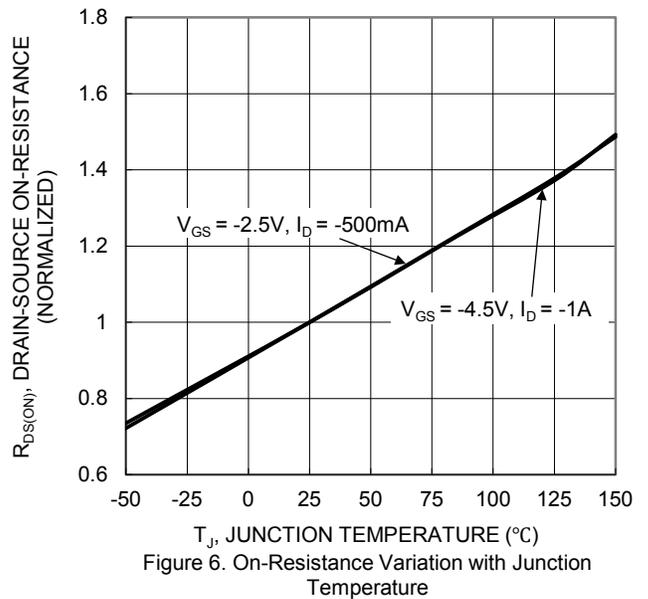
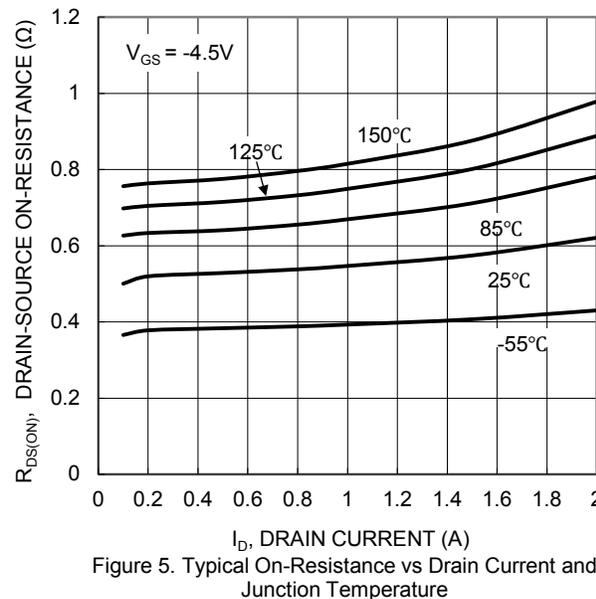
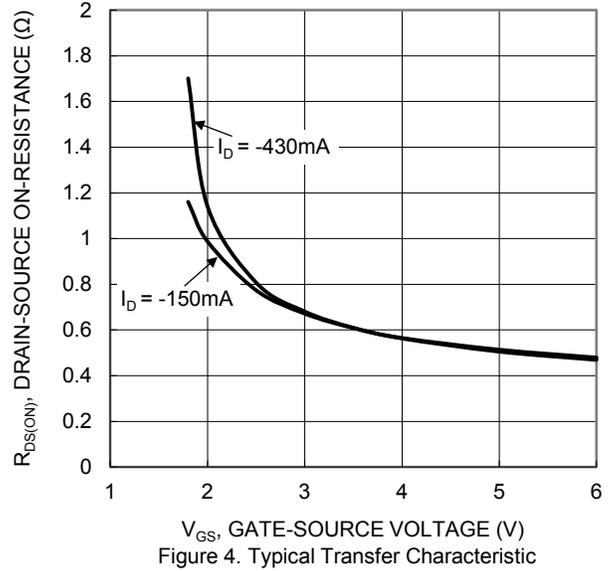
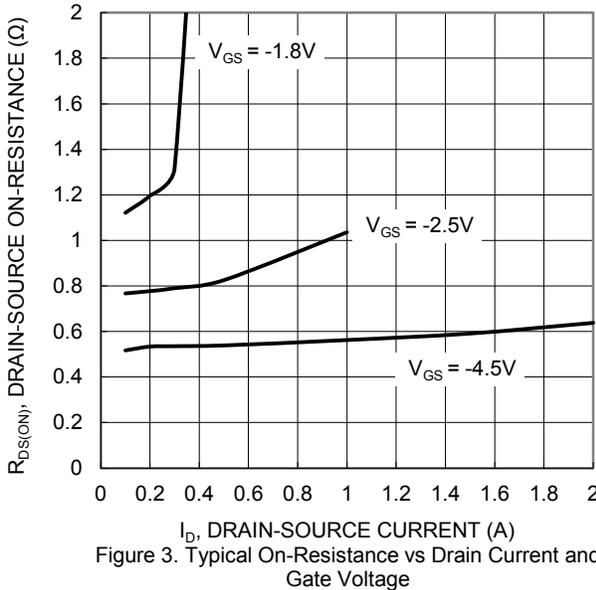
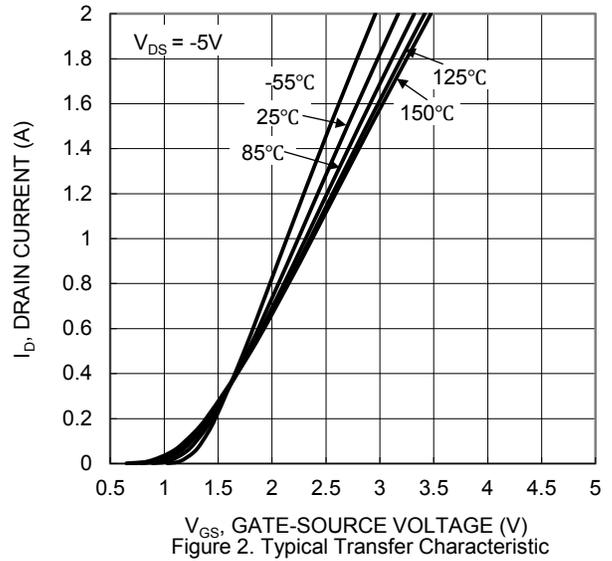
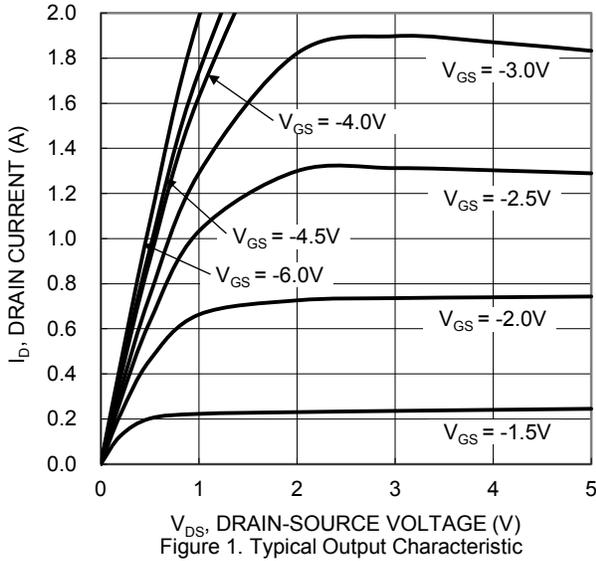
Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5)		$P_D$	0.31	W
Thermal Resistance, Junction to Ambient		$R_{\theta JA}$	398	$^\circ\text{C/W}$
Operating and Storage Temperature Range		$T_{J, STG}$	-55 to +150	$^\circ\text{C}$

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.  
 6. Repetitive rating, pulse width limited by junction temperature.

**Electrical Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 7)</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	-20	-	-	V	$V_{GS} = 0V, I_D = -250\mu\text{A}$
Zero Gate Voltage Drain Current $T_J = +25^\circ\text{C}$	$I_{DSS}$	-	-	-100	nA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	$I_{GSS}$	-	-	$\pm 2.0$	$\mu\text{A}$	$V_{GS} = \pm 4.5V, V_{DS} = 0V$
<b>ON CHARACTERISTICS (Note 7)</b>						
Gate Threshold Voltage	$V_{GS(TH)}$	-0.5	-	-1.0	V	$V_{DS} = V_{GS}, I_D = -250\mu\text{A}$
Static Drain-Source On-Resistance	$R_{DS(ON)}$	-	0.5	0.75	$\Omega$	$V_{GS} = -4.5V, I_D = -430\text{mA}$
		-	0.7	1.05		$V_{GS} = -2.5V, I_D = -300\text{mA}$
		-	1.0	1.5		$V_{GS} = -1.8V, I_D = -150\text{mA}$
		-	-	-		-
Forward Transfer Admittance	$ Y_{fs} $	-	0.9	-	S	$V_{DS} = -10V, I_D = -250\text{mA}$
Diode Forward Voltage	$V_{SD}$	-	-0.8	-1.2	V	$V_{GS} = 0V, I_S = -150\text{mA}$
<b>DYNAMIC CHARACTERISTICS (Note 8)</b>						
Input Capacitance	$C_{iss}$	-	59.76	-	pF	$V_{DS} = -16V, V_{GS} = 0V, f = 1.0\text{MHz}$
Output Capacitance	$C_{oss}$	-	12.07	-	pF	
Reverse Transfer Capacitance	$C_{rss}$	-	6.36	-	pF	
Total Gate Charge	$Q_g$	-	622.4	-	pC	$V_{GS} = -4.5V, V_{DS} = -10V, I_D = -250\text{mA}$
Gate-Source Charge	$Q_{gs}$	-	100.3	-	pC	
Gate-Drain Charge	$Q_{gd}$	-	132.2	-	pC	
Turn-On Delay Time	$t_{D(ON)}$	-	5.1	-	ns	$V_{DD} = -10V, V_{GS} = -4.5V, R_L = 47\Omega, R_G = 10\Omega, I_D = -200\text{mA}$
Turn-On Rise Time	$t_R$	-	8.1	-	ns	
Turn-Off Delay Time	$t_{D(OFF)}$	-	28.4	-	ns	
Turn-Off Fall Time	$t_F$	-	20.7	-	ns	

Notes: 7. Short duration pulse test used to minimize self-heating effect.  
 8. Guaranteed by design. Not subject to production testing.



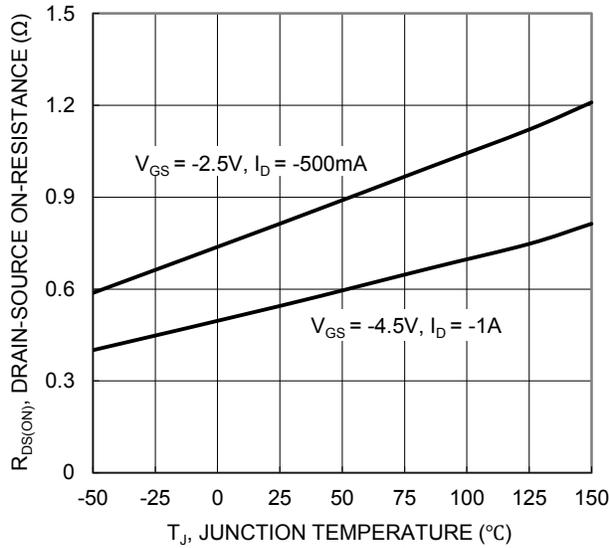


Figure 7. On-Resistance Variation with Junction Temperature

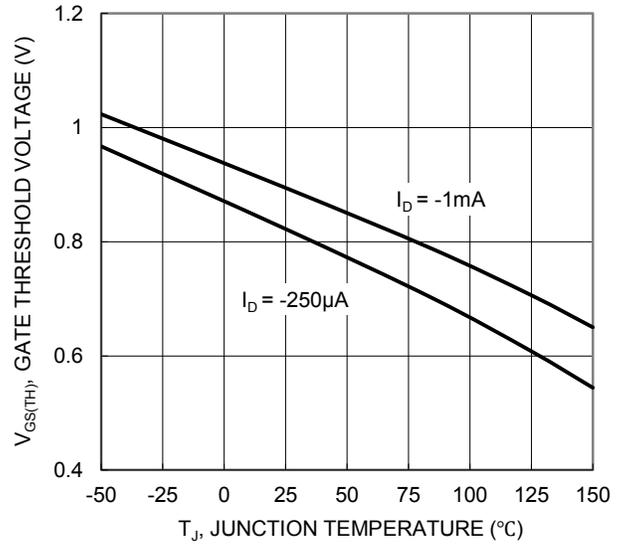


Figure 8. Gate Threshold Variation vs Junction Temperature

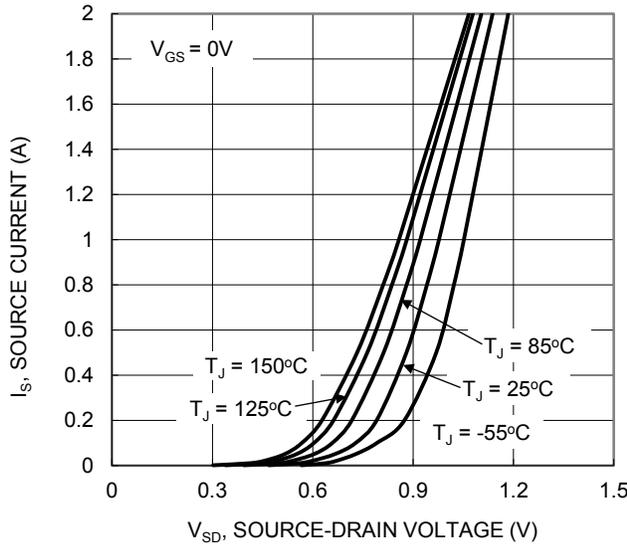


Figure 9. Diode Forward Voltage vs Current

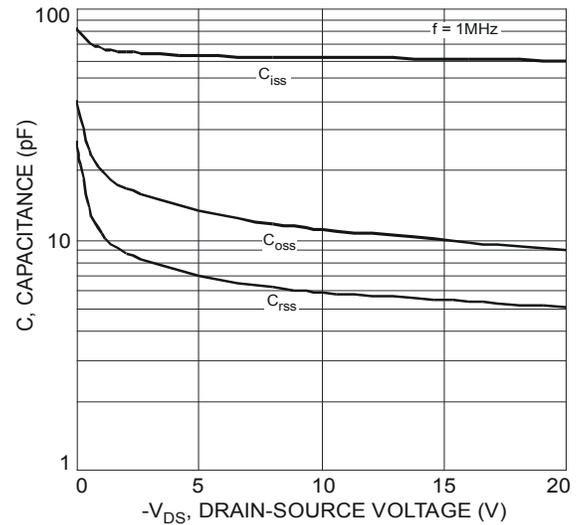


Figure 10. Typical Total Capacitance

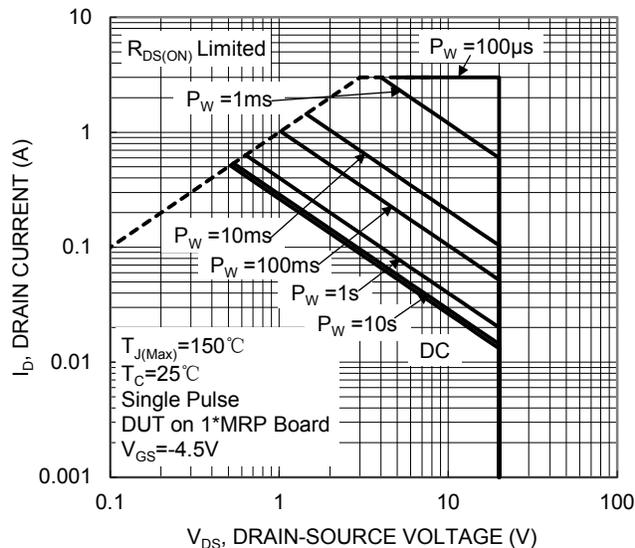


Figure 11. SOA, Safe Operation Area

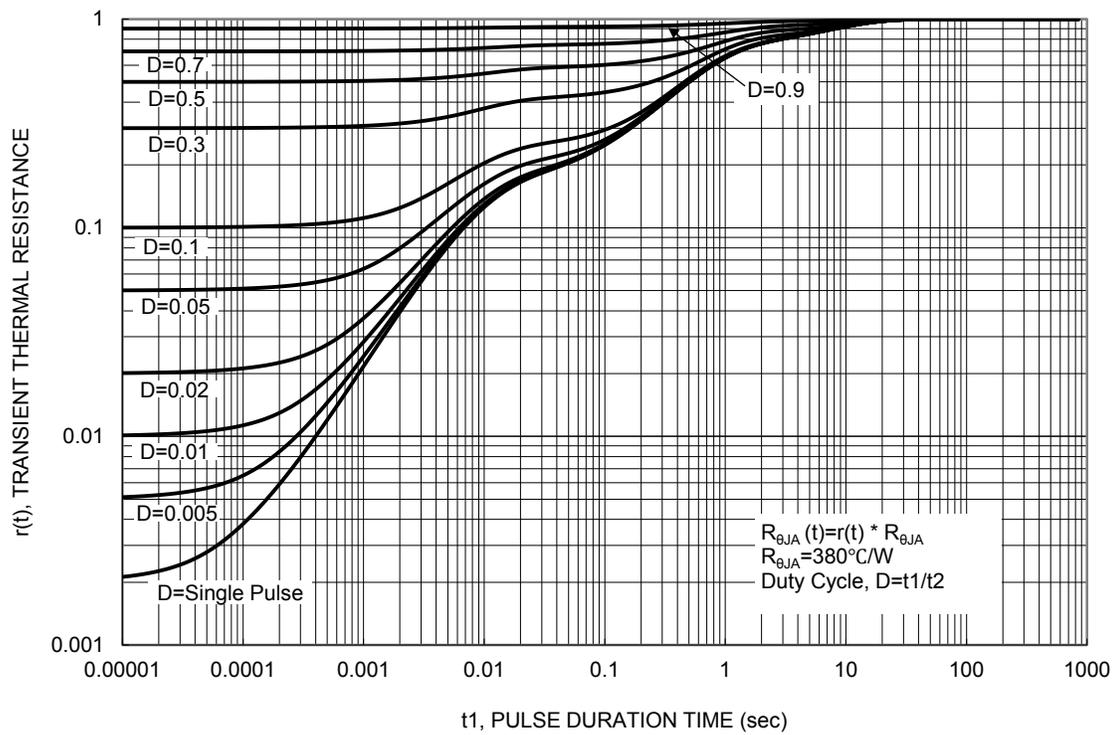
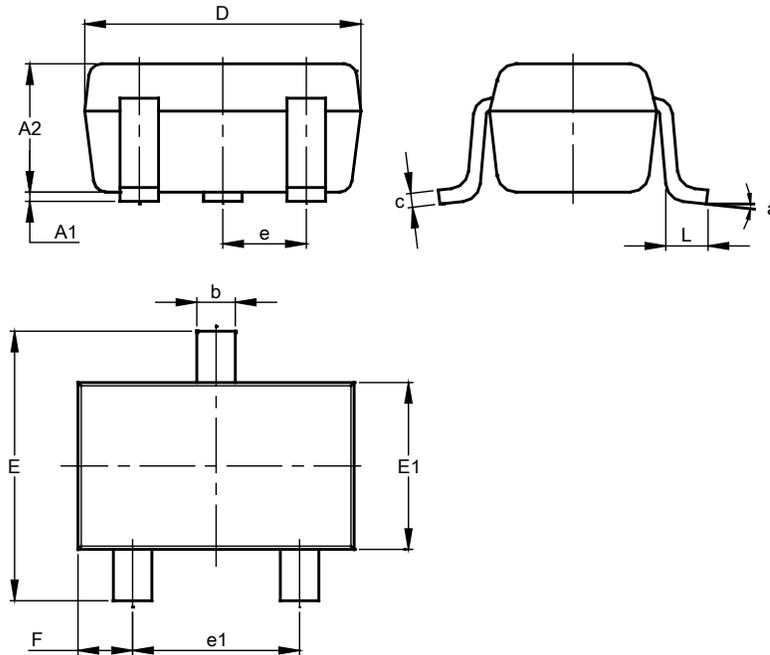


Figure 12. Transient Thermal Resistance

## Package Outline Dimensions

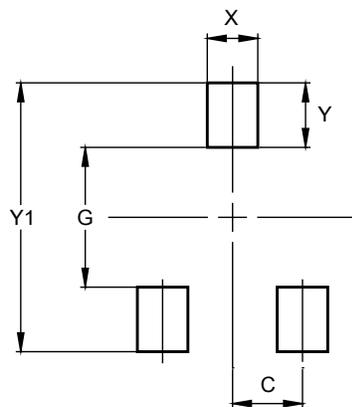
SOT323



SOT323			
Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.25	0.40	0.30
c	0.10	0.18	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
e1	1.20	1.40	1.30
F	0.375	0.475	0.425
L	0.25	0.40	0.30
a	8°		
All Dimensions in mm			

## Suggested Pad Layout

SOT323



Dimensions	Value (in mm)
C	0.650
G	1.300
X	0.470
Y	0.600
Y1	2.500